

**H11A1X, H11A2X, H11A3X, H11A4X, H11A5X
H11A1, H11A2, H11A3, H11A4, H11A5**

**OPTICALLY COUPLED
ISOLATOR
PHOTOTRANSISTOR OUTPUT**



APPROVALS

- UL recognised, File No. E91231
- 'X' SPECIFICATION APPROVALS
- VDE 0884 in 3 available lead forms : -
 - STD
 - G form
 - SMD approved to CECC 00802
- Certified to EN60950 by the following Test Bodies : -
 - Nemko - Certificate No. P96101299
 - Fimko - Registration No. 190469-01..22
 - Semko - Reference No. 9620076 01
 - Demko - Reference No. 305567

DESCRIPTION

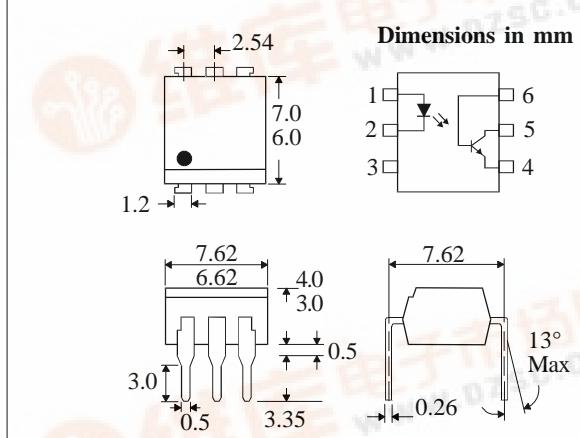
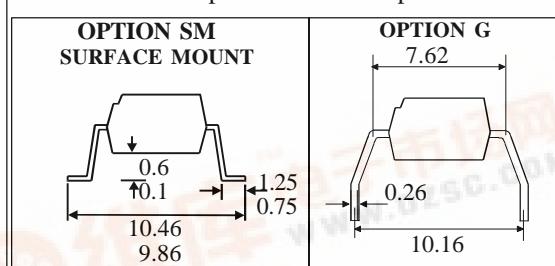
The H11A series of optically coupled isolators consist of infrared light emitting diode and NPN silicon photo transistor in a standard 6 pin dual in line plastic package.

FEATURES

- Options :-
10mm lead spread - add G after part no.
Surface mount - add SM after part no.
Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

- DC motor controllers
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



**ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)**

Storage Temperature	_____	-55°C to + 150°C
Operating Temperature	_____	-55°C to + 100°C
Lead Soldering Temperature	(1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	_____	60mA
Reverse Voltage	_____	6V
Power Dissipation	_____	105mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV _{CEO}	_____	30V
Collector-base Voltage BV _{CBO}	_____	70V
Emitter-collector Voltage BV _{ECO}	_____	6V
Power Dissipation	_____	160mW

POWER DISSIPATION

Total Power Dissipation	_____	200mW
(derate linearly 2.67mW/°C above 25°C)		

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F) Reverse Voltage (V_R) Reverse Current (I_R)	6	1.2	1.5	V V μA	$I_F = 10\text{mA}$ $I_R = 10\mu\text{A}$ $V_R = 6\text{V}$
Output	Collector-emitter Breakdown (BV_{CEO}) (note 2) Collector-base Breakdown (BV_{CBO}) Emitter-collector Breakdown (BV_{ECO}) Collector-emitter Dark Current (I_{CEO}) Collector-base Dark Current (I_{CBO})	30 70 6 50 20			V V V nA nA	$I_C = 1\text{mA}$ $I_C = 100\mu\text{A}$ $I_E = 100\mu\text{A}$ $V_{CE} = 10\text{V}$ $V_{CE} = 10\text{V}$
Coupled	Current Transfer Ratio (CTR) H11A1 H11A2 H11A3 H11A4 H11A5 Collector-emitter Saturation Voltage $V_{CE(SAT)}$ Input to Output Isolation Voltage V_{ISO} Input-output Isolation Resistance R_{ISO} Output Rise Time t_r Output Fall Time t_f	50 20 20 10 30 5300 7500 5×10^{10}		0.4	% % % % % V V_{RMS} V_{PK} Ω μs μs	10mA I_F , 10V V_{CE} 10mA I_F , 0.5mA I_C See note 1 See note 1 $V_{IO} = 500\text{V}$ (note 1) $V_{CC} = 10\text{V}$, $I_C = 2\text{mA}$ $R_L = 100\Omega$ fig 1

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

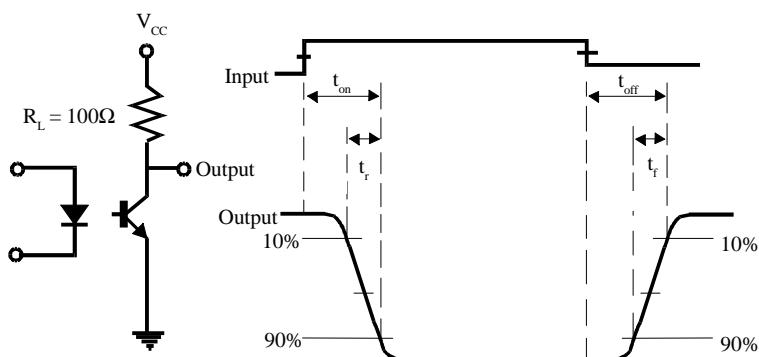


FIG 1



